IECQ-CECC **QC 88000-C001**

COMPONENT **ISSUE 2**

SPECIFICATION **March 2007**

Component Specification For Ceramic Hermetically Sealed Transistor Optocouplers

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FOREWORD

The IECQ Quality Assessment System for Electronic Components (IECQ) is composed of those member countries of the International Electrotechnical Commission (IEC) who wish to take part in a harmonized system for electronic components of assessed quality. IECQ is also known in some European member countries as IECQ-CECC.

The object of the System is to facilitate international trade by the harmonization of the specifications and quality assessment procedures for electronic components, and by the grant of an internationally recognised Mark, or Certificate of Conformity. The components produced or services provided under the system are thereby acceptable in all member countries without further testing.

This Component Specification is based upon the requirements of IEC Publication QC 001002-2, and has been prepared by:

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and published under the authority of:

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AMENDMENT RECORD

No previous issue.

REQUIREMENTS

The requirements for IECQ-CECC Component Specifications as detailed in QC 001002-2 Amendment 1 clause 5.4 are satisfied by the following data sheet.

It should note that IECQ-CECC are not responsible for manufacturers declarations made in data sheets which fall outside the limits of approved detailed in IECQ-CECC certificates.

This Component Specification is intended for use with applicable IECQ-CECC Assessment Specifications. Eg: QC 88000-A0001

ISOCOM® LTD

Ceramic Hermetically Sealed Transistor Optocouplers

- 4N24
- CD500/501
- CH300
- CS200/201
- CS224
- CSM165
- CSM200
- CSM1200
- CSM1224

Features

- Release to IECQ-CECC
- Hermetically Sealed
- High Density Packaging
- 1500V DC withstand Test Voltage
- Low Input Requirements
- High Current Transfer Ratio

Applications

- Military, high reliability system
- Medical instruments
- Mos, Cmos Applications
- Logic Interfacing
- Data Transmission
- Power Supply
- Modems

Description

These devices are single, dual and quad, hermetically sealed optocouplers. Each channel is composed of a Gallium Arsenide infra-red emitting diode and a silicon phototransistor. Package styles for these devices include 6 pin, 8 pin, 16 pin flat pack, and hybrid 4 pin, with surface mount, butt cut and gull wing options available.

The same electrical die, assembly processes and materials are used for each channel of each device shown below. Therefore absolute maximum ratings, recommended operating conditions, electrical specifications and performance characteristics are identical for all units. Any exceptions, due to packaging variations and limitations, are as noted.

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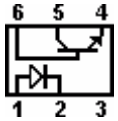
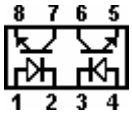
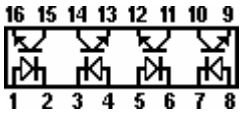
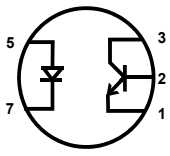
Selection Guide Package Styles and Configuration Options

Package	6 pin DIP	6 pin DIP	6 pin LCC	8 pin DIP	16 pin Flat Pack	6 pin Metal Can TO-5
Lead Style						
Channels	1	1	2	2	4	1
Common Channel Wiring						
Isocom Part Numbers and Options						
Commercial	CS200/201	CS224 CS200	CSM200 CSM1200/1244	CD500 CD501	CSM165	4N24
Defense Screen Level	CM200/201/L2	CS224 CS200/L2	CSM200/L2 CSM1200/1244/L2	CD500/L2 CD501/L2	CSM165/L2	4N24/L2
Space Screen Level	CS200/201/L2S	CS224 CS200/L2S	CSM200/L2S CSM1200/1244/L2S	CD500/L2S CD501/L2S	CSM165/L2S	4N24/L2S
Standard Gold Plate Finish	Gold Plate	Gold Plate	Gold Plate	Gold Plate	Gold Plate	Gold Plate
Solder Dipped	Option 20	Option 20	Option 20	Option 20		
Butt Cut/Gold Plate	Option 10	Option 10	Option 10	Option 10		
Gull Wing/Solered	Option 30	Option 30	Option 30	Option 30		
Crew Cut/Gold Plate	Option 60	Option 60	Option 60	Option 60		

Functional Diagrams

CH300 CSM200	CS200/201 CSM1200	CS224 CSM1224	CD500 CD501	CSM165/2/4
	6 pin DIP	6 pin DIP	8 pin DIP	16 pin Flat Pack
1 Channel	1 Channel	1 Channel	2 Channel	2*/4 Channel
				

4N24
6 pin TO-5
1 Channel


* Note 2 channel is only for circuit of 2 middle channels 2 & 3 channel on the circuits.

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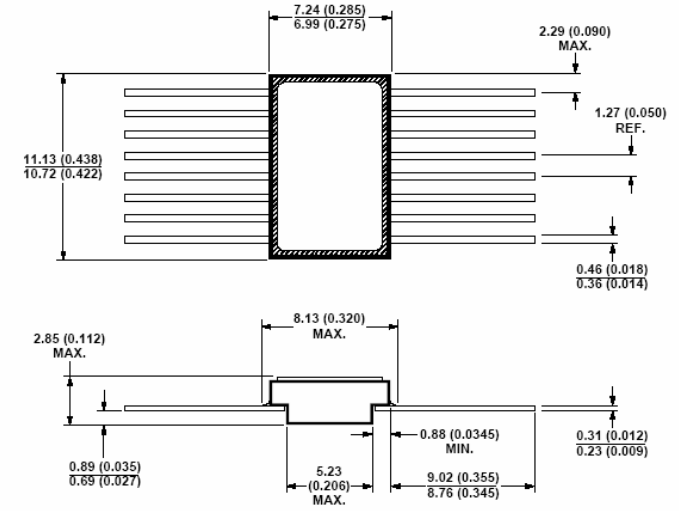
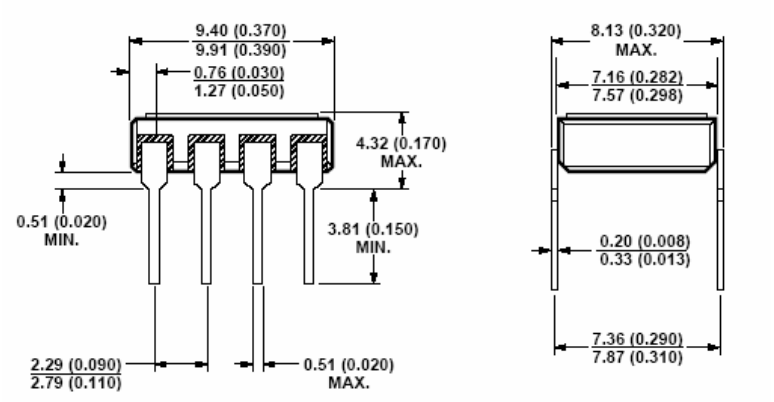
Outline Drawings

16 pin Flat Pack, 4 Channel



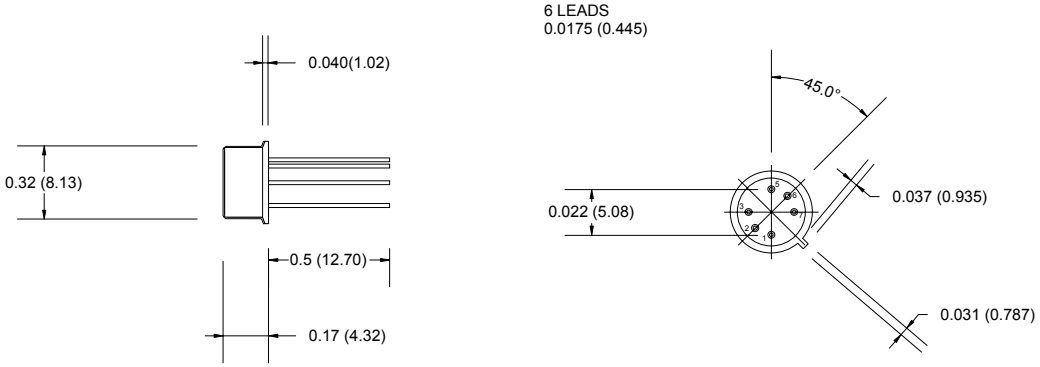
NOTE: DIMENSIONS IN MILLIMETERS

8 pin DIP 2 Channel



NOTE: DIMENSIONS IN MILLIMETERS

6 pin TO-5, 1 Channel



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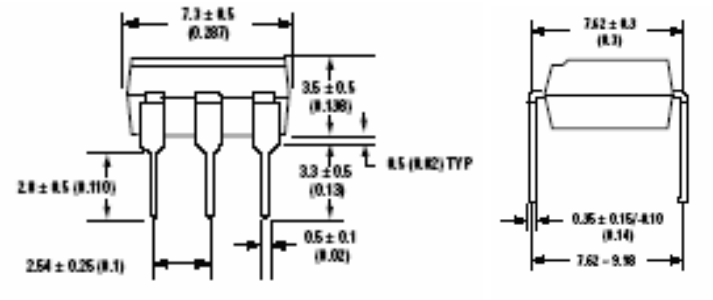
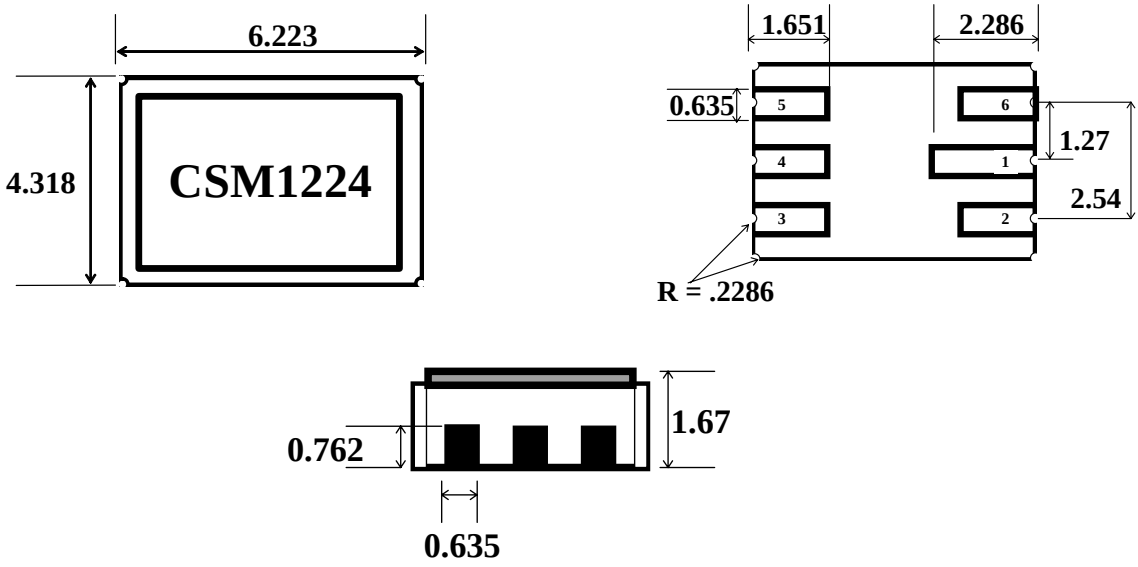
6 pin DIP 1 channel

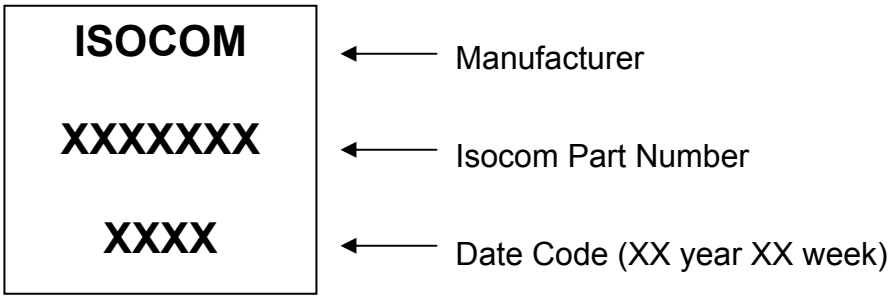


NOTE: DIMENSIONS IN MILLIMETERS

6 Terminal LCC Surface Mount, 1 Channel



Device Marking



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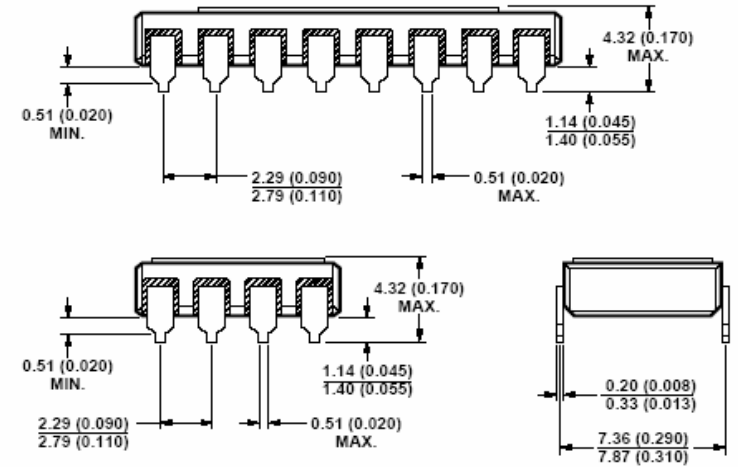
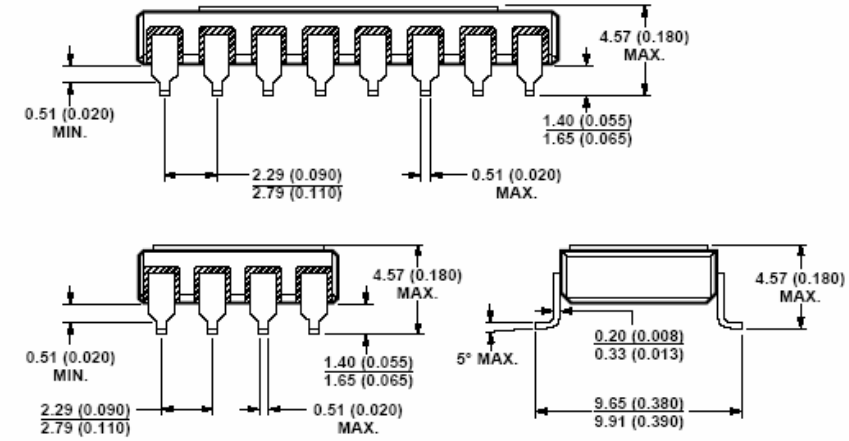
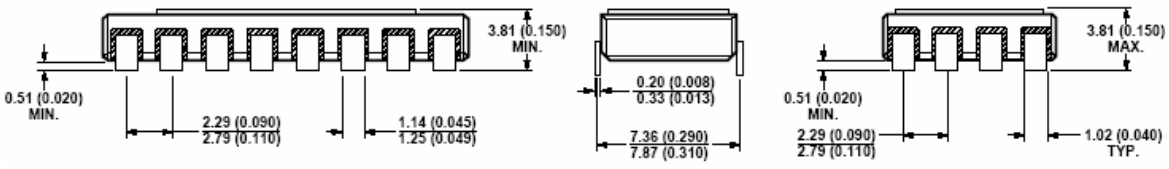
Hermetic Optocoupler Options

Option	Description
10	Surface mountable hermetic optocoupler with leads trimmed for butt joint assembly. This option is available on commercial hi-rel product in 8 and 16 pin DIP 
20	
30	Surface mountable hermetic optocoupler with leads cut and bent for gull wing assembly. This option is available on commercial and hi-rel product in 8 and 16 pin DIP. 
60	Surface mountable hermetic optocoupler with leads trimmed for butt joint assembly. This option is available on commercial hi-rel product in 8 and 16 pin DIP 

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Absolute Maximum Ratings

Storage Temperature	-65°C to +150°C
Operating Temperature	-55°C to +125°C
Lead Soldering Temperature	260°C 1.6mm from case for 10S
Input-to-Output Isolation Voltage	⇧1500VDC
	⇧500VDC for CH300

Input Diode

Forward DC Current	50mA	
	15mA	For CH300
Reverse DC Voltage	7V	
	5V	For CH300
	3V	For CSM165
	2V	For CS224
Peak forward Current	1.5mA	≤ 10µS duration
Power Dissipation	100mW	Derate linearly above 100°C at 1.6W/°C.
	150mW	For CD500/501 andCSM165. Derate linearly above 100°C at 1.4W/°C for CD500/501, and at 1.6 W/°C for CSM165
	25mW	For CH300

Output Transistor

Collector-Emitter Voltage	50V	BV_{CEO}
	30V	For CH300
	35V	For CS224
Emitter-Collector Voltage	7V	BV_{ECO}
Collector-Base Voltage	70V	BV_{CBO} For CS200/201 and CS224
	35V	For CS224
Collector Current	50mA	
	20mA	For CH300
Collector Current	100mA	t = 1mS
Power Dissipation	100mW	For CH300. Derate linearly above 100°C at 1.4W/°C
	150mW	For CS200/201, CS224, CD500/501 and CSM165. Derate linearly above 100°C at 1.4W/°C

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Electrical Characteristics

T_A = 25°C U.O.S. (each channel where appropriate).

Input Diode Electrical Characteristics

Parameter	Symbol	Test Conditions	Device	Min	Type	Max	Units
Forward Voltage	V_F	I_F = 10mA		0.7	1.18	1.6	V
		I_F = 10mA, T_A = 125°C		0.7	1.10	1.6	
		I_F = 10mA, T_A = -55°C		0.7	1.29	1.6	
Reverse Breakdown Voltage	V_R	I_R = 0.1mA		5	-	-	V
Reverse Current	I_R	V_R = 3V		-	-	100	µA
Capacitance	C_{IN}	V = 0, f = 1MHz		-	25	-	pF

Output Detector Electrical Characteristics

Collector-Emitter Breakdown Voltage (See note 1 below)	BV_{CEO}	I_C = 1mA	CH300	40 30	-	-	V
Collector-Base Breakdown Voltage (See note 1 below)	BV_{CBO}	I_B = 0.1mA		70	-	-	V
Emitter-Collector Breakdown Voltage	BV_{ECO}	I_E = 0.1mA		7	-	-	V
Emitter-Base Breakdown Voltage	BV_{EBO}	I_B = 0.1mA		5	-	-	V
Collector-Emitter Leakage Current	I_{CEO}	V_{CE} = 20V, I_F = 0 V_{CE} = 15v I_F = 0	CSM165	-	6	100	µA
		V_{CE} = 20V, I_F = 0, T_A = 125°C		-	8	100	µA

Coupled Electrical Characteristics

DC Current Transfer Ratio (See note 3)	IC/IF	I_F = 10mA, V_{CE} = 5V	CS201	50 100	-	-	%
		I_F = 10mA, V_{CE} = 5V, T_A = 125°C	CS201	50	-	-	
		I_F = 10mA, V_{CE} = 5V, T_A = -55°C	CS201	50	-	-	
		I_F = 10mA, V_{CE} = 5V; T_A = -55°C-125°C		35	-	-	
Optical Crosstalk	I_{CEOX}	V_{CE} = 15v, , I_F2-4 = 10mA.	CSM165			250	µA
Collector-Emitter Saturation Voltage	V_{CE} (Sat)	I_F = 10mA, I_C = 2.5mA		-	-	0.3	V
		I_F = 10mA, I_C = 10A	CSM165			0.9	
		I_F = 2mA, I_C = 0.2mA	CH300			0.25	
Input to Output Capacitance	C_{IO}	V_{IO} = 0, f = 1mhz (See note 2 below)		-	3	5	pF
Input to Output Resistance	R_{IO}	V_{IO} = 500V (See note 2 below)		-	10^{11}	-	Ω
Isolation Voltage	V_{IO}	(See note 2 below)	CH300	1500 500	-	-	VDC
Delay Time	td	V_{CC} = 5V, I_C = 2mA		-	4.0		µS
Rise Time	tr	R_L = 100Ohms		-	5.0		µS
Storage Time	ts			-	0.7		µS
Fall Time	tf			-	5.0		µS
Turn -on Time	t_{on}	V_{CC} = 5V, I_f = 5mA		-	9		µS
Turn-off Time	t_{off}	R_L = 1KOhms		-	25		µS

Notes:

1. BV_{CEO} and BV_{CBO} can be selected to suit customer specifications.
2. Measured between input when leads 1, 2 and 3 are shorted together and output when leads 4, 5 and 6 are shorted together.
3. A higher CTR can be selected to suit customer specification as a standard part.

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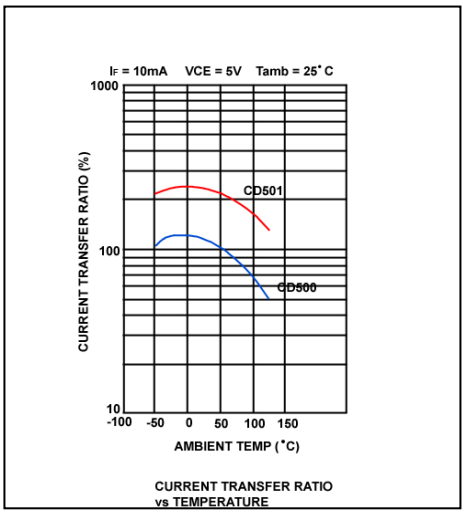
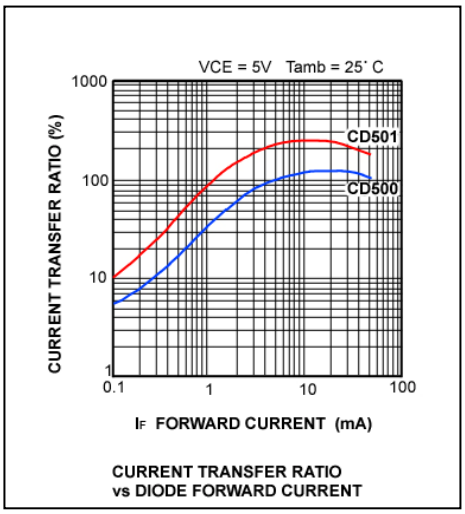
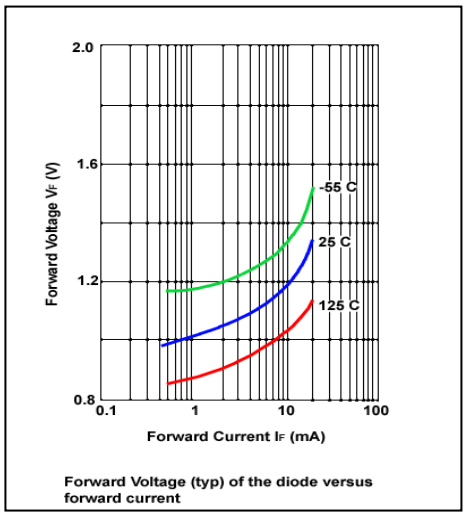
Electrical Characteristics



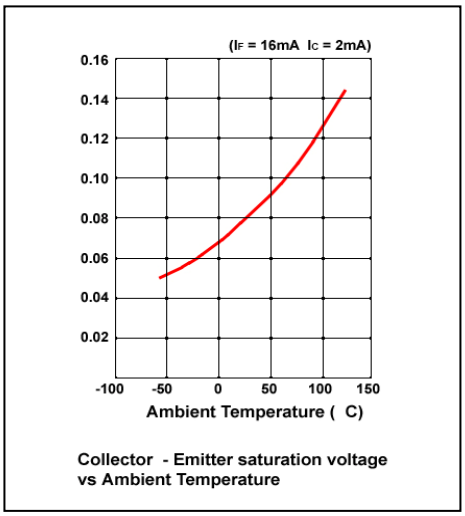
CURRENT TRANSFER RATIO vs TEMPERATURE



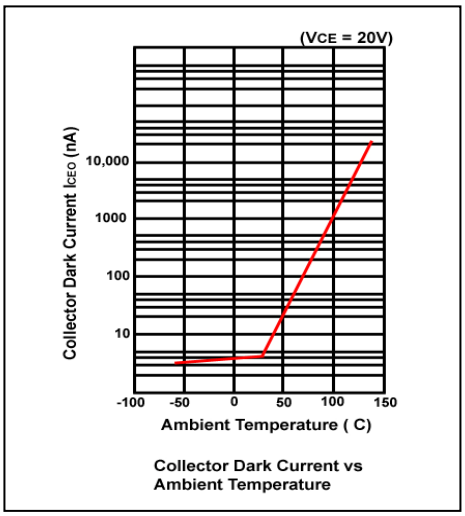
CURRENT TRANSFER RATIO vs DIODE FORWARD CURRENT



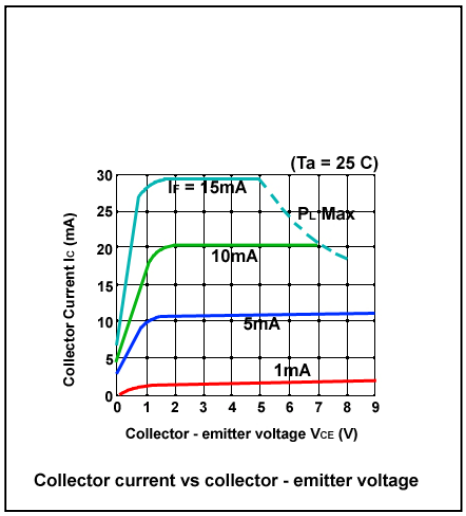
Forward Voltage (typ) of the diode versus forward current



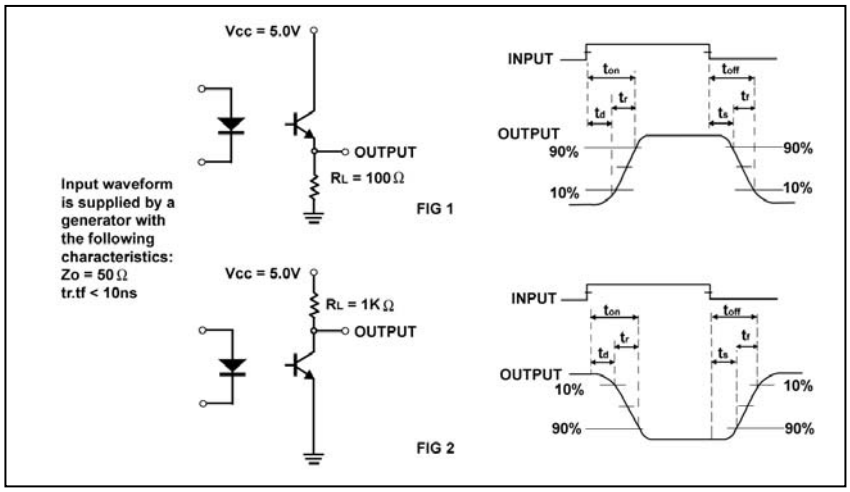
Collector - Emitter saturation voltage vs Ambient Temperature



Collector Dark Current vs Ambient Temperature



Collector current vs collector - emitter voltage



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